

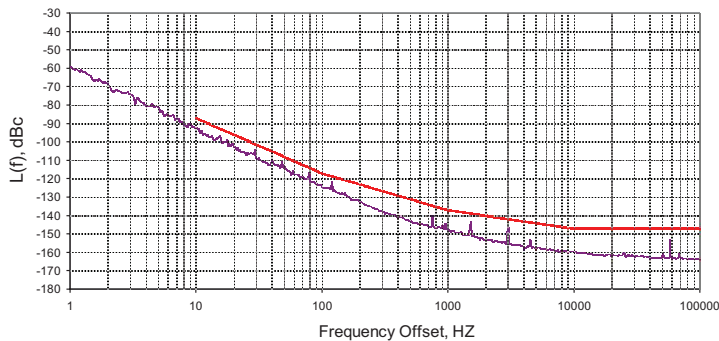
REVISIONS

REVISION	DESCRIPTION	APPROVED	DATE
-	Initial Release	Luis Vargas	6/5/2008
A	Updated part numbers	Luis Vargas	1/9/09

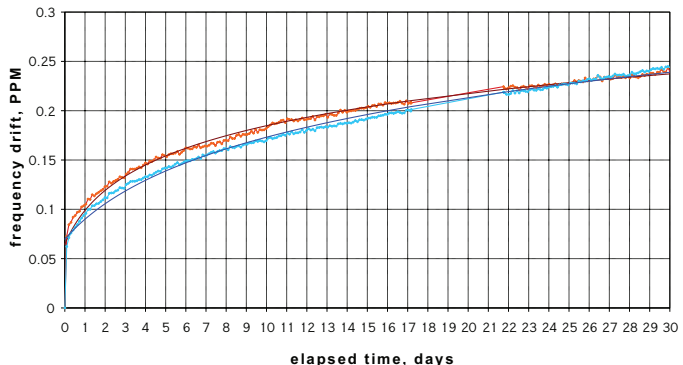
GENERAL RELEASE DOCUMENT

CONSULT FACTORY FOR CURRENT REVISION

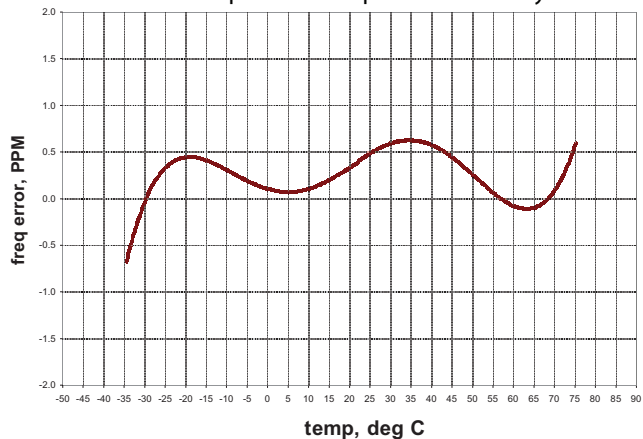
50MHz TCXO ,V_{cc}=12v,+25°C
9/17/08



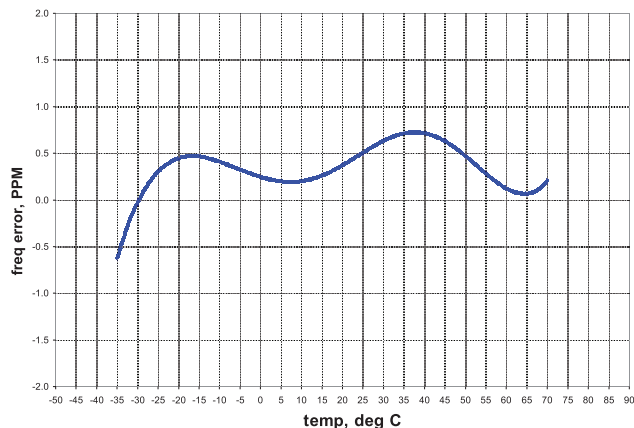
Aging Data



Example 1 of Temperature Stability



Example 2 of Temperature Stability



SPECIFICATION CONTROL DRAWING

UNLESS OTHERWISE SPECIFIED, DIMENSIONS ARE IN INCHES.

TOLERANCES:
3 PLACE DECIMAL = .005
2 PLACE DECIMAL = .02
1 PLACE DECIMAL = .1
FRACTIONS = ± 1/16
ANGLES = 2 DEGREES

RELEASED BY:
DOCUMENT CONTROL

PREPARED BY:
Luis Vargas
DATE
6/5/08

CHECKED BY:
QUALITY
DATE

APPROVED BY:
ENGINEERING
DATE

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**LOW PROFILE 24 PIN DDIP HYBRID CRYSTAL OSCILLATOR,
TCXO, CLASS S,
Standard Design For HCMOS up to 90MHz**

DRAWING NO.:	REVISION
QT801 and QT802 Square-Wave	A

SCALE	SIZE	CAGE CODE	SHEET 1 of 8
NONE	A	51774	

1.0 SCOPE

This specification establishes the detail requirements for low profile hybrid, hermetically sealed, HCMOS output temperature compensated crystal oscillators (TCXO) for use in space flight missions.

2.0 APPLICABLE DOCUMENTS

The following documents of the latest issue form a part of this drawing to the extent specified herein.

2.1 Specifications and Standards

SPECIFICATIONS	
MILITARY	
MIL-S-19500	Semiconductor Devices, General Specification For
MIL-PRF-55310	Crystal Oscillators, General Specification For
MIL-PRF-38535	Integrated Circuits, (Microcircuits) Manufacturing, General Specification For
MIL-PRF-38534	Hybrid Microcircuits, General Specification For
STANDARDS	
MILITARY	
MIL-STD-202	Test Methods for Electronic and Electrical Component Parts
MIL-STD-883	Test Methods and Procedures for Microelectronics
MIL-STD-1686	Electrostatic Discharge Control Program for Protection of Electrical and Electronics Parts, Assemblies and Equipment.

2.2 Conflicting Requirements

In the event of conflict between requirements of this specification and other requirements of the applicable detail drawing, the precedence in which requirements shall govern, in descending order, is as follows:

- a) Applicable customer purchase order.
- b) Applicable detail drawing.
- c) This specification.
- d) Other specifications or standards referenced in 2.1 herein.

2.3 Customer Purchase Order Special Requirements

Additional special requirements shall be specified in the applicable Customer purchase order when additional requirements or modifications specified herein are needed for compliance to special program or product line requirements.

3.0 PERFORMANCE REQUIREMENTS

3.1 General Definition

The TCXO is a high reliability signal generator that provides a square-wave output. The TCXO has been designed to operate in a spaceflight environment with an expected lifetime in excess of 15 years. Lifetime is defined as the sum of operational and storage environments.

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3.1.1 Electrical Characteristics

PARAMETER	SYMBOL	CONDITIONS	VALUE	UNIT	
Frequency Nom.	fo	-	2. to 90	MHz	
Supply voltage, Nom.	Vs	Vs±5%	See part number generation table	V	
Input Current, max.	Is	Vs, nom. / Ta=+25°C	50	mA	
Freq. stability vs. temperature (including ±5% Load Change and ±5% Input Voltage change)	Δf/fc (Ta)	Contact factory for other options available	See part number generation table	ppm	
Electrical Frequency Adjustment Min. (when specified)	Δf/fo (ΔVcc)	±5 PPM <u>Two options:</u> 1) via an external select-at-test resistor connected from Pin 1 to Ground 2) Via External tuning voltage	±5.0	ppm	
Aging Max	Δf/fo	over 10 year (first year ≤ 1 ppm)	±5.0	ppm	
Freq. stability vs. Vacuum	Δf/fo	Met by design, not tested	±0.2	ppm	
Short term stability	Δf/fc(Δt)	Δt=1sec. (Allan variance)	0.001	ppm	
RF Output		Contact factory for other options available	30 to 70 3rd	70.1 to 90 3 rd X	MHz
Output	VOH / VOL	load=15pF, Vcc=nom.	0.9•Vcc / 0.1•Vcc	V	
Duty cycle	DC	load=15pF/ @50%Vcc, Ta=+25°C	See part number generation table	%	
Rise- / fall time	tr / tf	20%~80% Vout, 80%~20% Vout	.5...7 (see note A)	nSec	
Load			15	pF	
Phase noise @ freq. offset	£ (Δf)	Δf=10Hz	-75	Contact factory for other options available	dBc/Hz
	£ (Δf)	Δf=100Hz	-105		dBc/Hz
	£ (Δf)	Δf=1kHz	-130		dBc/Hz
	£ (Δf)	Δf=10kHz	-140		dBc/Hz
	£ (Δf)	Δf=100kHz	-140		dBc/Hz

A: **Supply Current, rise & fall time are frequency dependent**

3.2 Absolute Maximum Rating

Supply Voltage	0 to +6.0 VDC
DC Input Current	50 mA maximum
Storage Temperature range	-62°C to +125°C
Lead Temperature (Soldering, 10 seconds)	300°C

3.2.1 Physical Characteristics

3.2.1.1 Dimensions - The TCXO outline dimensions and terminal connections shall be as shown in Figure 1 herein.

3.2.1.2 Weight - The TCXO shall weigh less than or equal to 15 grams.

3.2.1.3 Materials - The TCXO package body and lead finish shall be gold in accordance with MIL-PRF-38534.

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3.2.2 Environmental Conditions

Sine Vibration	MIL-STD-202, Method 204, TC "D"
Random Vibration	MIL-STD-202, Method 214 TC "I-K" (15 minutes per axis)
Shock	MIL-STD-202, Method 213, TC "F"
Acceleration	MIL-STD-883, Method 2001, TC "A"
Altitude	50,000 feet minimum to deep space
Radiation	Radiation testing is not performed, but these TCXOs have been acceptable for use in environments up to 100K rads by analysis of the components used. Bipolar semiconductors are employed in combination with a CMOS microcircuit in this part and shall be from a wafer proven to be radiation tolerant to 100 kRad (Si) total ionizing dose. This device is specified to be single event latchup free for LET up to 93 MeV-cm ² /mg.. A copy of the parts list and materials can be provided for review.
Electrostatic Discharge Sensitivity	The TCXO supplied to this drawing shall be considered to be electrostatic discharge sensitive and require further protection and shall use one of the packaging requirements in accordance with MIL-PRF-38534, Category A, Section 5.3.2.4 Transportability. The TCXO shall be capable of being transported by air, ship or road when packaged in a suitable container.

3.3 Design and Construction

The design and construction of the crystal oscillator shall be as specified herein. As a minimum, the oscillators shall meet the design and construction requirements of MIL-PRF-55310, except element evaluation shall be as specified in 3.3.1.

Operation	
Design, Construction & Component Screen (see 3.3.2)	MIL-PRF-55310 Class S
Workmanship	M883, Method 2017 for Class S
Screening	MIL-PRF-55310 Class S
Non-Destruct Wire Bond Pull	100%, M883, Method 2023 (2.4 grams)
Internal Visual	MIL-STD-883, methods 2017 & 2032 condition K (class S). During the time interval between final internal visual inspection and preparation for sealing, hybrid crystal oscillators shall be stored in a dry, controlled environment as defined in MIL-STD-883, method 2017 or in a vacuum bake oven.
Stabilization Bake	48 hrs minimum @ +150 C M883, Method 1008 TC B
Thermal Shock	M883, Method 1011, TC A
Temperature Cycling	M883, Method 1010, TC B
Constant Acceleration	M883, Method 2001, TC A (5000 gs, Y1 Axis only)
Seal Test (fine & gross)	100% Method 1014, (TC A1 for fine leak and TC C for gross leak)
PIND	M883, Method 2020, TC B
Electrical Test	Frequency, Output levels, Input Current@ +25 C
Burn-In (Powered with load)	+125 C for 240 hours
Electrical Test	Frequency, Output levels, Input Current @ +25°C & Temp Extremes listed on the Electrical Specification
Radiographic	M883, Method 2012 class S
Group A	100%
Group B (30 day Aging @ +70 C)	100%
External visual	883 Method 2009

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3.3.1 All piece parts shall be derived from lots that meet the element evaluation requirements of MIL-PRF-38534, Class K with the following exceptions:

Active elements

- a) Visual inspection of silicon on sapphire microcircuits. Semicircular crack(s) or multiple adjacent cracks, not in the active area, starting and terminating at the edge of the die are acceptable. Attached (chip in place) sapphire is nonconductive material and shall not be considered as foreign material and will be considered as nonconductive material for all inspection criteria.
- b) Subgroup 4, Scanning Electron Microscope (SEM) inspection. The manufacturer may allow the die distributor, at his option, to select two (2) dice from a waffle pack (containing a maximum quantity of 100 die), visually inspect for the worst case metallization of the 2 dice, and take SEM photographs of the worst case.
- c) Subgroup 5 radiation tests. Subgroup 5 radiation tests are not required unless otherwise specified in the detail purchase order.

3.3.2 Processes - Processes used for manufacturing the TCXO are selected on the basis of their ability to meet the quality requirements for space High Reliability manufacturing. Travelers or Process Cards are used in the manufacturing and testing of all of the TCXO Series, and might be available for customer review. Copies of these Travelers can be provided with the TCXOs at time of shipment if so specified on the purchase order.

3.3.3 Interchangeability - Each TCXO shall be interchangeable without using a special selection process.

3.3.4 Product Marking - Each unit shall be permanently marked with the manufacturer's name or symbol, part number, lot date code number, and serial number. The unit shall be marked with the outline of an equilateral triangle near pin 1 to show that it contains devices which are sensitive to electrostatic discharge.

3.4 Parts Program

Devices delivered to this specification represent the standardized Parts, Materials and Processes (PMP) Program developed, implemented and certified for advanced applications and extended environments.

3.4.1 Quartz Crystal Resonator - The crystal resonator used shall be constructed using premium synthetic swept Quartz and procured to Q-TECH SCD. For the Engineering models, non-swept quartz may be used.

3.5 Traceability Requirements

Material, element and process traceability requirements shall be as specified by MIL-PRF-38534 for Class K hybrids.

3.6 Data

3.6.1. Design Documentation - When required by the purchase order, design, topography, process and flow charts for all assembly/inspection and test operation for devices to be supplied under this specification on the initial procurement shall be established and shall be available in-plant for review by the procuring activity upon request. This design documentation shall be sufficient to depict the physical and electrical construction of the devices supplied under the specification and shall be traceable to the specific parts, drawings or part type numbers to which it applies, and to the production lot(s) and inspection lot codes under which devices are manufactured and tested so that revisions can be identified.

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3.6.2. Technical Data Package. When required by the purchase order, the following design documentation and information is deliverable 30 days prior to the start of production. The Technical Data Package shall consist of the following:

- a) Assembly drawing(s).
- b) All electrical schematics and drawings *not considered proprietary*.
- c) The assembly and screening travelers to be used on-line to manufacture the devices supplied to this specification.
- d) Parts and materials list.

3.7 Test Report

A test report is supplied with each shipment of oscillators and includes the following information, as a minimum:

- a) A Certificate of Conformance to all specifications and purchase order requirements. As a minimum, the Certificate of Conformance shall include the following information:
 - Purchase order number.
 - Applicable part number.
 - Manufacturer’s lot number.
 - Lot date code.
- b) Parts and materials traceability information.
- c) Certificate of crystal sweeping.
- d) Manufacturing lot traveler.
- e) Screening attributes and variables data as applicable.
- f) Quality conformance inspection attributes and variables data as applicable.
- g) Radiographic inspection negatives.

3.8 Engineering Models

Engineering Models are fit, form, and function representative of Flight Models and of commercial construction using commercial parts of same generic type as Flight Models. Completed oscillators are not screened.

NOTES:

This oscillator is offered to meet the specifications above and is not guaranteed to meet any other requirements.

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■ **PART NUMBER GENERATION**

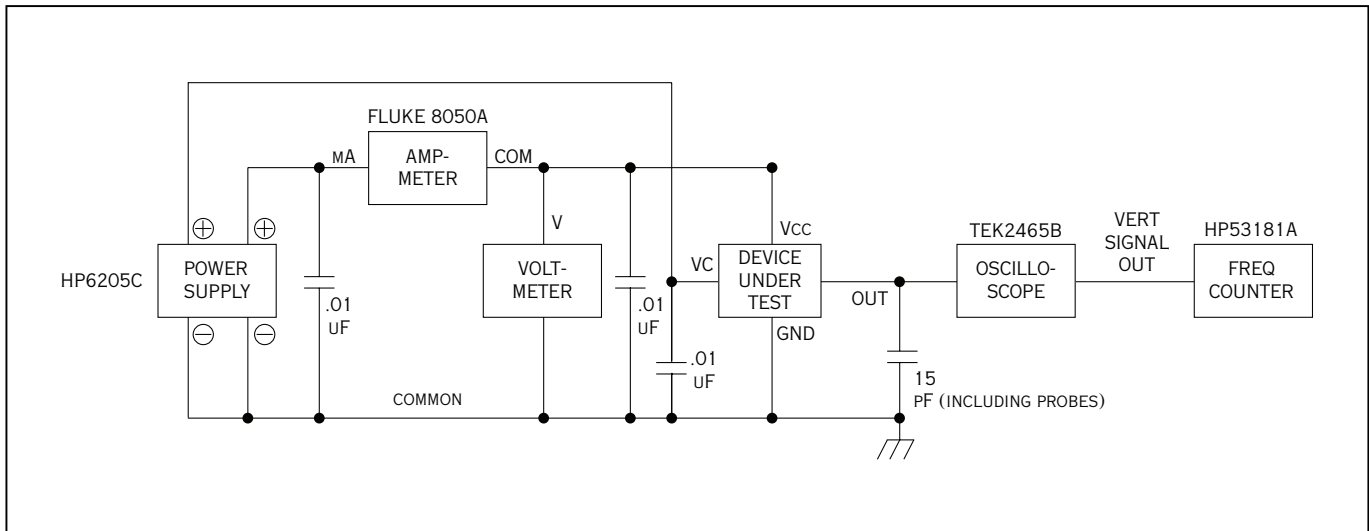
Engineering Models are designated by adding "E" in front of the part number.

SERIES	Output type and supply voltage	SYMMETRY	TEMPERATURE RANGE (°C)	STABILITY (Overall)	FREQUENCY (MHz)	External Tuning	
QT80: 24 Pin Double Dip	1. HCMOS....5.0V	A: 40%...60%	N: 0...+50.....	±1 ppm	2.000...90.000 (See note 1)	X: No tuning	
	2. HCMOS....3.3V	T: (See note 2)	P: 0...+70.....	±1 ppm		R: External resistor	
			Q: 0...+70.....	±2 ppm		V: External voltage	
			R: 0...+70.....	±5 ppm			
			U: -20...+70.....	±1 ppm			
			V: -20...+70.....	±2 ppm			
			W:-20...+70.....	±5 ppm			
			X: -40...+85.....	±4 ppm			
			Y: -40...+85.....	±5 ppm			
			Z: -40...+85.....	±10 ppm			
			(See note 1 below)				

1. Variations from standard specification are available, please contact factory.
2. 45/55 Symmetry Contact factory for options available.

EXAMPLE: The QT802AU-50.000000-R would be a HF TCXO, 24 pin SMD flat pack, HCMOS 3.3 volts, 40/60 symmetry, stability ±1 ppm over -20...+70°C, @ 50 MHz with external tuning via external resistor

■ **RECOMMENDED ELECTRICAL TEST DIAGRAM**



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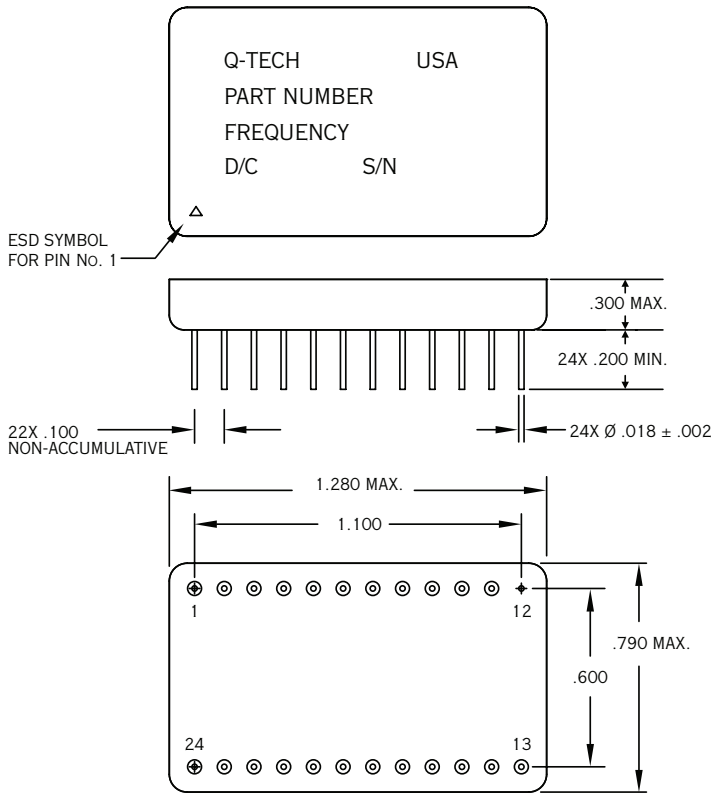
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**FIGURE 1 INTERFACE CONTROL DRAWING
24 Pin Double Dip**



PIN NO.	DESIGNATION
1	External Frequency Adjustment (when specified)
2 - 11	NC
12	Ground/Case
13	RF Output
14 - 23	NC
24	Supply Voltage

NOTES:

- Dimensions are in inches.
- Lead numbers are for reference only and are not marked on the unit.
- A triangle symbol is marked on the corner of the package to indicate Pin 1.
- All pins with NC function may not be connected as external tie or connections (pins may be connected internally).